

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Katsuhide MANABE, et al.

Serial No.: 09/677,781

Group Art Unit: 2812

Filing Date: October 2, 2000

Examiner: Mulpuri, Savitri

For: A METHOD FOR MANUFACTURING A GALLIUM NITRIDE GROUP  
COMPOUND SEMICONDUCTOR

Assistant Commissioner of Patents

Washington, D.C. 20231

**SUPPLEMENTAL REVOCATION OF POWER OF ATTORNEY  
AND APPOINTMENT OF NEW ATTORNEY**

Sir:

Nagoya University hereby certifies, pursuant to 37 C.F.R. § 3.73(b), that it is a joint assignee of the entire right, title and interest in the patent application identified above by virtue of an assignment from the inventor of the patent application identified above. The Assignment was recorded in the Patent and Trademark Office in Parent Application No. 09/417,778, filed on October 14, 1999.

The undersigned has reviewed all the documents in the chain of title of the patent application identified above and, to the best of undersigned's knowledge and belief, joint title is in the assignee identified above.

The undersigned, whose signature and title appear below, is empowered to act on behalf of Nagoya University, a joint assignee of the entire right, title, and interest of the present application.

I, the undersigned, hereby revoke all previous powers of attorney given in the above-identified application for letters patent, which application was filed on October 2, 2000, for an invention entitled "A METHOD FOR MANUFACTURING A GALLIUM NITRIDE GROUP

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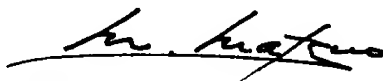
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Revocation of Power of Attorney - Nagoya University  
U.S. Application No. 09/677,781  
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COMPOUND SEMICONDUCTOR", Serial No. 09/677,781, and I hereby appoint Sean M. McGinn, Reg. No. 34,386, of McGinn & Gibb, PLLC, 8321 Old Courthouse Road, Suite 200, Vienna, Virginia 22182-3817, (703) 761-4100, as our attorney to prosecute said application, and to transact all business in the Patent and Trademark Office connected therewith.

I hereby declare that all statements made herein of my own knowledge are true, and that all statements made on information and belief are believed to be true; and further, that these statements are made with the knowledge that willful false statements, and the like so made, are punishable by fine or imprisonment, or both, under Section 1001, Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Date: March 12, 2003

 (Signature)  
\_\_\_\_\_  
Minoru Matsuo (Typed Name)  
\_\_\_\_\_  
President (Title)  
\_\_\_\_\_  
NAGOYA UNIVERSITY



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Assistant Commissioner of Patents

Washington, D.C. 20231

**SUPPLEMENTAL REVOCATION OF POWER OF ATTORNEY  
AND APPOINTMENT OF NEW ATTORNEY**

Sir:

Japan Science and Technology Corporation hereby certifies, pursuant to 37 C.F.R. § 3.73(b), that it is a joint assignee of the entire right, title and interest in the patent application identified above by virtue of an assignment from the inventor of the patent application identified above. The Assignment was recorded in the Patent and Trademark Office in Parent Application No. 09/417,778, filed on October 14, 1999.

The undersigned has reviewed all the documents in the chain of title of the patent application identified above and, to the best of undersigned's knowledge and belief, joint title is in the assignee identified above.

The undersigned, whose signature and title appear below, is empowered to act on behalf of Japan Science and Technology Corporation, a joint assignee of the entire right, title, and interest of the present application.

I, the undersigned, hereby revoke all previous powers of attorney given in the above-identified application for letters patent, which application was filed on October 2, 2000, for an invention entitled "A METHOD FOR MANUFACTURING A GALLIUM NITRIDE GROUP

COMPOUND SEMICONDUCTOR", Serial No. 09/677,781, and I hereby appoint Sean M. McGinn, Reg. No. 34,386, of McGinn & Gibb, PLLC, 8321 Old Courthouse Road, Suite 200, Vienna, Virginia 22182-3817, (703) 761-4100, as our attorney to prosecute said application, and to transact all business in the Patent and Trademark Office connected therewith.

I hereby declare that all statements made herein of my own knowledge are true, and that all statements made on information and belief are believed to be true; and further, that these statements are made with the knowledge that willful false statements, and the like so made, are punishable by fine or imprisonment, or both, under Section 1001, Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Date: *Mar 7, 2003*



(Signature)

Naotaka Oki

(Typed Name)

Vice President

(Title)

JAPAN SCIENCE AND TECHNOLOGY  
CORPORATION